TV East/West correction circuit for square tubes

Technology: Bipolar

Features

- Low dissipation
- Square generator for parabolic current specially designed for square C.R.T. correction
- External keystone adjustment (symmetry of the parabola)
- Input for dynamic field correction (beam current change)
- Static picture width adjustment
- Pulse-width modulator
- Final stage D-class with energy redelivery
- Parasitic parabola suppression, during flyback time of the vertical sawtooth

Case: 8 pin dual inline plastic

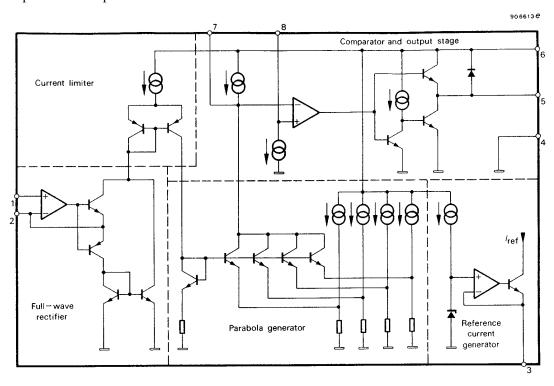


Figure 1 Block diagram

Absolute Maximum Ratings

	Parameters	Symbol	Value	Unit
Supply voltage	Pin 6	V_{S}	35	V
Supply current	Pin 6	I_S	500	mA
Substrate current	Pin 5	$-I_5$	400	mA
Power dissipation	$T_{case} = 50^{\circ}C$	P _{tot}	500	mW
Storage temperature rang	e	T_{stg}	-25 to +150	°C
Junction temperature		Tj	-25 to +150	°C

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Electrical Characteristics

 $V_S = 26V$, $T_{amb} = 25$ °C, Test circuits 1 to 5

Parameters	Test Conditions	s / Pins	Symbol	Min.	Тур.	Max.	Unit
Supply voltage range		Pin 6	V_{S}	17	24	30	V
Supply current	Test circuit 1	Pin 6	I_S		4.5	7	mA
Reference voltage	Test circuit 1	Pin 3	V _{ref}	7.6	8.0	8.8	V
Voltage at pin 7 *	$I_{fr} = 0 \mu A$, Test circuit 2	Pin 7	V _{7A}	15.3	16.0	16.7	V
Voltage at pin 7 *	I _{fr} = 30 μA, Test circuit 2	Pin 7	V _{7C}		15.0		V
Parabola coefficient *	$K_1 = \frac{V_{7A} - V_{7B}}{V_{7A} - V_{7C}}$		K ₁		28		%
Parabola coefficient *	$K_2 = \frac{V_{7A} - V_{7C}}{V_{7A} - V_{7D}}$		K ₂		71		%
Difference *	$V_{DE7} = V_{7E} - V_{7F}$			-40	0	40	mV
Current source	Test circuit 3	Pin 8	I ₈		100		μΑ
Saturation voltage	I ₅ = 400 mA, Test circuit 4	Pin 5	V _{satL}		1	2	V
Saturation voltage	$I_5 = -100 \text{ mA},$ Test circuit 5	Pin 5	V _{satH}		0.8	1.5	V
Forward voltage	I ₅ = 400 mA, Test circuit 5	Pin 5	V_{F}		1.2	1.7	V
Forward voltage (substrate diode)	$I_5 = -100 \text{ mA},$ Test circuit 4	Pin 5	V ₅		0.8	1.2	V

^{*} see figure 2

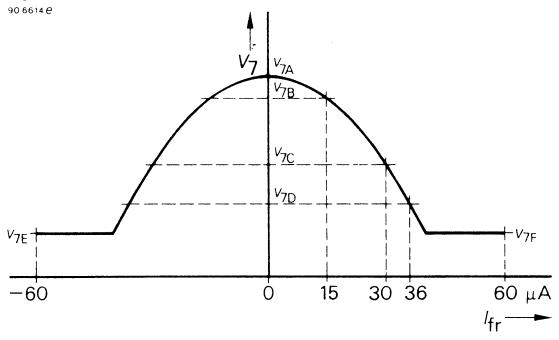


Figure 2 Parabola coefficients

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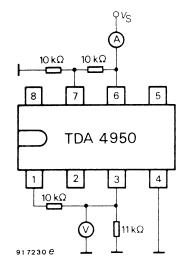


Figure 3 Test circuit 1

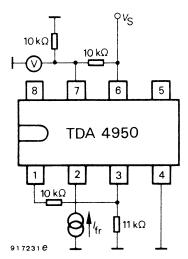


Figure 4 Test circuit 2

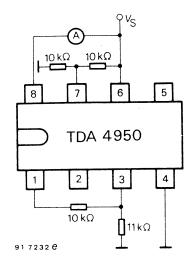


Figure 5 Test circuit 3

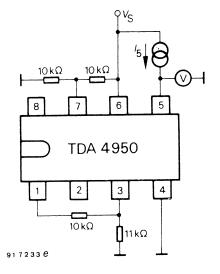


Figure 6 Test circuit 4

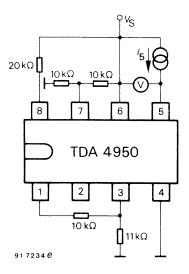
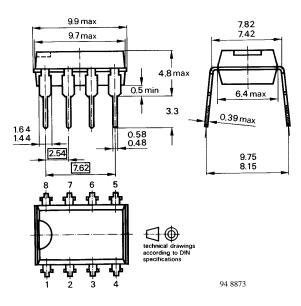


Figure 7 Test circuit 5

Dimensions in mm

Package: DIP 8



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